

PRODUCT SELECTION GUIDE

Samsung Semiconductor, Inc.

MEMORY & STORAGE

2H 2010





Samsung Semiconductor, Inc.

Samsung offers the industry's broadest memory portfolio and has maintained its leadership in memory technology for 16 straight years. Its DRAM, flash and SRAM products are found in computers—from ultra-mobile portables to powerful servers—and in a wide range of handheld devices such as smartphones and MP3 players. Samsung also delivers the industry's widest line of storage products. These include optical and hard disk drives as well as flash storage, such as the all-flash Solid State Drive and a range of embedded and removable flash storage products.

| Markets | DRAM | SRAM | FLASH | ASIC | LOGIC | TFT/LCD | ODD/HDD |
|----------------------------|------|------|-------|------|-------|---------|---------|
| Mobile/Wireless | | | | | | | |
| Notebook PCs | н | | | | | | |
| Desktop PCs/Workstations | | | | | | | |
| Servers | | | | | | | |
| Networking/ Communications | | | | | | | |
| Consumer Electronics | | | | | | | |

www.samsung.com/us/business/components



Pages 4-13

www.samsung.com/semi/dram

- DDR3 SDRAM
- DDR2 SDRAM
- DDR SDRAM
- SDRAM
- Mobile SDRAM
- RDRAM

• Graphics DDR SDRAM

• DRAM Ordering Information



FLASH

Pages 14-16

www.samsung.com/semi/flash

- SLC Flash
- MLC Flash
- SD and microSD Cards
- Flash Ordering Information

HIGH SPEED SRAM

Pages 17-20

www.samsung.com/semi/sram

- Asychronous
- Synchronous
- NtRAM™
- Late-Write R-R SRAM
- DDR / II / II+ SRAM
- QDR / II / II+ SRAM

MULTI-CHIP PACKAGE

Pages 21-22

www.samsung.com/semi/mcp

- NAND & DRAM
- OneNAND & DRAM
- Flex-OneNAND & DRAM
- OneNAND & DRAM & OneDRAM
- moviNAND & NAND & DRAM

NOR & UtRAM

NOR & DRAM

Fusion Memory

Pages 23

www.samsung.com/semi/fusion

- moviNAND™
- OneDRAM™

STORAGE

Pages 24-27

SSE

www.samsungssd.com

SATA SSD

Hard Drive

www.samsung.com/hdd

Optical Disc

www.samsungodd.com



DDR3 SDRAM REGISTERED MODULES

| Density | Voltage | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Ranks | Production |
|---------|---------|--------------|----------------------------------|-------------------------|--------------------------|--------------|-------|------------|
| 1GB | 1.5V | 128Mx72 | M393B2873FH0-C(F8/H9/K0*)(04/05) | 1Gb (128M x8) * 9 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 2GB | 1.5V | 256Mx72 | M393B5673FH0-C(F8/H9/K0*)(04/05) | 1Gb (128M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| ZUD | 1.00 | 230IVIX/ Z | M393B5670FH0-C(F8/H9/K0*)(04/05) | 1Gb (256M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| | | | M393B5173FH0-CF8(04/05) | 1Gb (128M x8) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| 4GB | 1.5V | 512Mx72 | M393B5170FH0-C(F8/H9/K0*)(04/05) | 1Gb (256M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 40D | 1.50 | J1ZIVIX/Z | M393B5273CH0-C(F8/H9/K0*)(04/05) | 2Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| | | | M393B5270CH0-C(F8/H9/K0*)(04/05) | 2Gb (512M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 8GB | 1.5V | 1Gx72 | M393B1K73CH0-CF8(04/05) | 2Gb (256M x8) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| OUD | 1.50 | IUX/Z | M393B1K70CH0-C(F8/H9/K0*)(04/05) | 2Gb (512M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 16GB | 1.5V | 2Gx72 | M393B2K70CM0-CF8(04/05) | 4Gb DDP (1024M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| 32GB | 1.5V | 4Gx72 | M393B4G70AM0-CF8(04/05) | 8Gb DDP (2048M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| 1GB | 1.35V | 128Mx72 | M393B2873FH0-Y(F8/H9/K0*)(04/05) | 1Gb (128M x8) * 9 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 2GB | 1.35V | 256Mx72 | M393B5673FH0-Y(F8/H9/K0*)(04/05) | 1Gb (128M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| ZUD | 1.33V | 230IVIX/2 | M393B5670FH0-Y(F8/H9/K0*)(04/05) | 1Gb (256M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| | | | M393B5173FH0-YF8(04/05) | 1Gb (128M x8) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| 4GB | 1.35V | 512Mx72 | M393B5170FH0-Y(F8/H9/K0*)(04/05) | 1Gb (256M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 4UD | 1.337 | JIZIVIXIZ | M393B5273CH0-Y(F8/H9/K0*)(04/05) | 2Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| | | | M393B5270CH0-Y(F8/H9/K0*)(04/05) | 2Gb (512M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 8GB | 1.35V | 1Gx72 | M393B1K73CH0-YF8(04/05) | 2Gb (256M x8) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| OGD | 1.550 | TUAT Z | M393B1K70CH0-Y(F8/H9/K0*)(04/05) | 2Gb (512M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 16GB | 1.35V | 2Gx72 | M393B2K70CM0-YF8(04/05) | 4Gb DDP (1024M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| 32GB | 1.35V | 4Gx72 | M393B4G70AM0-YF8(04/05) | 8Gb DDP (2048M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |

NOTES:

F7 = DDR3-800 (6-6-6) F8 = DDR3-1066 (7-7-7) H9 = DDR3-1333 (9-9-9) K0 = DDR3-1600 (11-11-11)

04 = IDT B0 register 05 = Inphi C0 register * K0 (1600Mbps) available in ES only

DDR3 SDRAM VLP REGISTERED MODULES

| Density | Voltage | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Ranks | Production |
|---------|---------|--------------|------------------------------|-------------------------|--------------------------|--------------|-------|------------|
| 1GB | 1.5V | 128Mx72 | M392B2873FH0-C(F8/H9)(04/05) | 1Gb (128M x8) * 9 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 2GB | 1.5V | 256Mx72 | M392B5673FH0-C(F8/H9)(04/05) | 1Gb (128M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 200 | 1.50 | 230IVIX/ 2 | M392B5670FH0-C(F8/H9)(04/05) | 1Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| | | | M392B5170FM0-C(F8/H9)(04/05) | 2Gb DDP (512M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 4GB | 1.5V | 512Mx72 | M392B5273CH0-C(F8/H9)(04/05) | 2Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| | | | M392B5270CH0-C(F8/H9)(04/05) | 2Gb (512M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 8GB | 1.5V | 1Gx72 | M392B1K73CM0-CF8(04/05) | 4Gb DDP (512M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| OUD | 1.50 | TGX72 | M392B1K70CM0-C(F8/H9)(04/05) | 4Gb DDP (1024M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 16GB | 1.5V | 2Gx72 | M392B2G70AM0-C(F8/H9)(04/05) | 8Gb DDP (2048M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 1GB | 1.35V | 128Mx72 | M392B2873FH0-Y(F8/H9)(04/05) | 1Gb (128M x8) * 9 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 2GB | 1.35V | 256Mx72 | M392B5673FH0-Y(F8/H9)(04/05) | 1Gb (128M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 200 | 1.337 | 230IVIX/2 | M392B5670FH0-Y(F8/H9)(04/05) | 1Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| | | | M392B5170FM0-Y(F8/H9)(04/05) | 2Gb DDP (512M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 4GB | 1.35V | 512Mx72 | M392B5273CH0-Y(F8/H9)(04/05) | 2Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| | | | M392B5270CH0-Y(F8/H9)(04/05) | 2Gb (512M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 000 | 1.051/ | 10,70 | M392B1K73CM0-YF8(04/05) | 4Gb DDP (512M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| 8GB | 1.35V | 1Gx72 | M392B1K70CM0-Y(F8/H9)(04/05) | 4Gb DDP (1024M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 16GB | 1.35V | 2Gx72 | M392B2G70AM0-Y(F8/H9)(04/05) | 8Gb DDP (2048M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| NOTEC: | F= 0000 | 000 (0 0 0) | O.4 IDT DO serietes | | | | | |

F7 = DDR3-800 (6-6-6) F8 = DDR3-1066 (7-7-7) H9 = DDR3-1333 (9-9-9) NOTES:

04 = IDT B0 register 05 = Inphi C0 register

DDR3 SDRAM UNBUFFERED MODULES

| Density | Voltage | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Ranks | Production |
|---------|------------------|---------------------------|---------------------------|--------------------------|--------------------------|----------------|-------|------------|
| 1GB | 1.5V | 128Mx64 | M378B2873FH0-C(F8/H9/K0*) | 1Gb (128M x8) * 8 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| OCD. | 2GB 1.5V 256Mx64 | M378B5673FH0-C(F8/H9/K0*) | 1Gb (128M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now | |
| ZUD | | 230IVIX04 | M378B5773FH0-C(F8/H9/K0*) | 2Gb (256M x8) * 8 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 4GB | 1.5V | 512Mx64 | M378B5273CH0-C(F8/H9/K0*) | 2Gb (256M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 8GB | 1.5V | 1024Mx64 | M378B1G73AH0-C(F8/H9/K0*) | 4Gb (512M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |

DDR3 SDRAM UNBUFFERED MODULES (ECC)

| Density | Voltage | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Ranks | Production |
|---------|---------|--------------|---------------------------|--------------------|--------------------------|----------------|-------|------------|
| 1GB | 1.5V | 128Mx72 | M391B2873FH0-C(F8/H9/K0*) | 1Gb (128M x8) * 9 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 2GB | 1.5V | 256Mx72 | M391B5673FH0-C(F8/H9/K0*) | 1Gb (128M x8) * 18 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| ZUD | 1.50 | 230IVIX/ 2 | M391B5773FH0-C(F8/H9/K0*) | 2Gb (256M x8) * 9 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 4GB | 1.5V | 512Mx72 | M391B5273CH0-C(F8/H9/K0*) | 2Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 8GB | 1.5V | 1024Mx72 | M391B1G73AH0-C(F8/H9/K0*) | 4Gb (512M x8) * 18 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 1GB | 1.35V | 128Mx72 | M391B2873FH0-Y(F8/H9/K0*) | 1Gb (128M x8) * 9 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 2GB | 1.35V | 256Mx72 | M391B5673FH0-Y(F8/H9/K0*) | 1Gb (128M x8) * 18 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| ZUD | 1.557 | 230IVIX12 | M391B5773FH0-Y(F8/H9/K0*) | 2Gb (256M x8) * 9 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 4GB | 1.35V | 512Mx72 | M391B5273CH0-Y(F8/H9/K0*) | 2Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 8GB | 1.35V | 1024Mx72 | M391B1G73AH0-Y(F8/H9/K0*) | 4Gb (512M x8) * 18 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |

NOTES: F7 = DDR3-800 (6-6-6) F8 = DDR3-1066 (7-7-7) K0 = DDR3-1600 (11-11-11)

H9 = DDR3-1333 (9-9-9)

* K0 (1600Mbps) available in ES only

DDR3 SDRAM SODIMM MODULES

| Density | Voltage | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Ranks | Production |
|---------|---------|--------------|---------------------------|--------------------|--------------------------|----------------|-------|------------|
| 1GB | 1.5V | 128Mx64 | M471B2873FHS-C(F8/H9/K0*) | 1Gb (128M x8) * 8 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 2GB | 1.5V | 256Mx64 | M471B5673FH0-C(F8/H9/K0*) | 1Gb (128M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 200 | 1.50 | 230IVIX04 | M471B5773FHS-C(F8/H9/K0*) | 2Gb (256M x8) * 8 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 4GB | 1.5V | 512Mx64 | M471B5273CH0-C(F8/H9/K0*) | 2Gb (256M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 8GB | 1.5V | 1024Mx64 | M471B1G73AH0-C(F8/H9/K0*) | 4Gb (512M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 1GB | 1.35V | 128Mx64 | M471B2873FHS-Y(F8/H9/K0*) | 1Gb (128M x8) * 8 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 2GB | 1.35V | 256Mx64 | M471B5673FH0-Y(F8/H9/K0*) | 1Gb (128M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 200 | 1.337 | 230IVIX04 | M471B5773FHS-Y(F8/H9/K0*) | 2Gb (256M x8) * 8 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 4GB | 1.35V | 512Mx64 | M471B5273CH0-Y(F8/H9/K0*) | 2Gb (256M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 8GB | 1.35V | 1024Mx64 | M471B1G73AH0-Y(F8/H9/K0*) | 4Gb (512M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |

NOTES: F7 = DDR3-800 (6-6-6) K0 = DDR3-1600 (11-11-11) * K0 (1600Mbps) available in ES only

F8 = DDR3-1066 (7-7-7) H9 = DDR3-1333 (9-9-9)

DDR3 SDRAM COMPONENTS

| Density | Voltage | Organization | Part Number | # Pins-Package | Compliance | Speed (Mbps) | Dimensions | Production |
|---------|---------|--------------|----------------------------------|----------------|--------------------------|----------------|------------|------------|
| 1Gb | 1.5V | 256M x4 | K4B1G0446F-HC(F8/H9) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333 | 7.5x11mm | Now |
| TGD | 1.50 | 128M x8 | K4B1G0846F-HC(F8/H9/K0*) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333/1600 | 7.5x11mm | Now |
| | | 512M x4 | K4B2G0446C-HC(F8/H9) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333 | 7.5x11mm | Now |
| 2Gb | 1.5V | 256M x8 | K4B2G0846C-HC(F8/H9/K0*) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333/1600 | 7.5x11mm | Now |
| | | 128M x16 | K4B2G1646C-HC(F8/H9/K0*/MA*/NB*) | 96 Ball -FBGA | Lead Free & Halogen Free | 1066/1333/1600 | 7.5x13.3mm | Now |
| 1Gb | 1.35V | 256M x4 | K4B1G0446F-HC(F8/H9) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333 | 7.5x11mm | Now |
| TGD | 1.557 | 128M x8 | K4B1G0846F-HC(F8/H9/K0*) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333/1600 | 7.5x11mm | Now |
| 2Gb | 1.35V | 512M x4 | K4B2G0446C-HC(F8/H9) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333 | 7.5x11mm | Now |
| 200 | 1.337 | 256M x8 | K4B2G0846C-HC(F8/H9/K0*) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333/1600 | 7.5x11mm | Now |

NOTES: F7 = DDR3-800 (6-6-6)

F8 = DDR3-1066 (7-7-7) H9 = DDR3-1333 (9-9-9) MA = DDR3-1866 (13-13-13) NB = DDR3-2133 (14-14-14)

* KO, MA, and NB are available in ES only

K0 = DDR3-1600 (11-11-11)

DDR2 SDRAM REGISTERED MODULES

| Density | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Register | Rank | Production |
|--------------|--------------|-----------------------|--------------|------------|--------------|----------|------|------------|
| 1GB | 128Mx72 | M393T2863FBA-C(E6/F7) | (128M x8)*9 | Lead free | 667/800 | Υ | 1 | Now |
| 000 05044-70 | 256Mx72 | M393T5660FBA-C(E6/F7) | (256M x4)*18 | Lead free | 667/800 | Υ | 1 | Now |
| 2GB | 200IVIX/2 | M393T5663FBA-C(E6/E7) | (128M x8)*18 | Lead free | 667/800 | Υ | 2 | Now |
| 4GB | 512Mx72 | M393T5160FBA-C(E6/F7) | (256M x4)*36 | Lead free | 667/800 | Υ | 2 | Now |

NOTES:

E6=PC2-5300 (DDR2-667 @ CL=5)

F7=PC2-6400 (DDR2-800 @ CL=6)

E7=PC2-6400 (DDR2-800 @ CL=5)

Voltage = 1.8V

DDR2 SDRAM VLP REGISTERED MODULES

| Density | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Register | Rank | Production |
|---------|--------------|------------------|--------------|------------|--------------|----------|------|------------|
| 2GB | 256Mx72 | M392T5660FBA-CE6 | (256M x4)*18 | | Lead free | 667 | Υ | 1 |

DDR2 SDRAM FULLY BUFFERED MODULES

| Density | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Voltage | Rank | Production |
|---------|--------------|-------------------|--------------|------------|--------------|---------|------|------------|
| 2GB | 256Mx72 | M395T5663FB4-CE68 | (128M x8)*18 | Lead free | 667 | 1.8V | 2 | Now |
| 4CD | 512Mx72 | M395T5160FB4-CE68 | (256M x4)*36 | Lead free | 667 | 1.8V | 2 | Now |
| 4GB | 512Mx72 | M395T5163FB4-CE68 | (128M x8)*36 | Lead free | 667 | 1.8V | 4 | Now |

NOTES: E6 = PC2-5300 (DDR2-667 @ CL=5)

AMB = IDT L4

Voltage = 1.8V (AMB Voltage = 1.5V)

DDR2 SDRAM UNBUFFERED MODULES

| Density | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Rank | Production |
|---------|--------------|--------------------------|--------------|------------|--------------|------|------------|
| 1GB | 128Mx64 | M378T2863FBS-C(E6/F7/E7) | (128M x8)*8 | Lead free | 667/800 | 1 | Now |
| 2GB | 256Mx64 | M378T5663FB3-C(E6/F7/E7) | (128M x8)*16 | Lead free | 667/800 | 2 | Now |

NOTES: E6=PC2-5300 (DDR2-667 @ CL=5)

E7=PC2-6400 (DDR2-800 @ CL=5)

F7=PC2-6400 (DDR2-800 @ CL=6)

Voltage = 1.8V

DDR2 SDRAM UNBUFFERED MODULES (ECC)

| Density | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Rank | Production |
|---------|--------------|-----------------------|-------------|------------|--------------|------|------------|
| 1GB | 128Mx72 | M391T2863FB3-C(E6/F7) | (128Mx8)*9 | Lead free | 667/800 | 1 | Now |
| 2GB | 256Mx64 | M391T5663FB3-C(E6/F7) | (128Mx8)*18 | Lead free | 667/800 | 2 | Now |

NOTES: E6=PC2-5300 (DDR2-667 @ CL=5)

E7=PC2-6400 (DDR2-800 @ CL=5) F7=PC2-6400 (DDR2-800 @ CL=6)

Voltage = 1.8V

DDR2 SDRAM SODIMM MODULES

| Density | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Rank | Production |
|---------|--------------|--------------------------|-------------|------------|--------------|------|------------|
| 1GB | 128Mx64 | M470T2863FB3-C(E6/F7/E7) | (64Mx16)*8 | Lead free | 667/800 | 2 | Now |
| 2GB | 256Mx64 | M470T5663FB3-C(E6/F7/E7) | (128M x8)*8 | Lead free | 667/800 | 2 | Now |

NOTES:

E6=PC2-5300 (DDR2-667 @ CL=5) E7=PC2-6400 (DDR2-800 @ CL=5) F7=PC2-6400 (DDR2-800 @ CL=6)

Voltage = 1.8V

DDR2 SDRAM COMPONENTS

| Density | Organization | Part Number | # Pins-Package | Dimensions | Package | Speed (Mbps) | Production |
|---------|--------------|----------------------------|----------------|------------|--------------------------|--------------|------------|
| 256Mb | 16Mx16 | K4T56163QN-HC(E6/F7/E7/F8) | 84-FBGA | 7.5x12.5mm | Lead free & Halogen free | 667/800/1066 | Now |
| E4 OMI | 128M x4 | K4T51043QI-HC(E6/F7/E7) | 60-FBGA | 7.5x9.5mm | Lead free & Halogen free | 667/800 | Now |
| | 64M x8 | K4T51083QI-HC(E6/F7/E7/F8) | 60-FBGA | 7.5x9.5mm | Lead free & Halogen free | 667/800/1066 | Now |
| | 32M x16 | K4T51163QI-HC(E6/F7/E7/F8) | 84-FBGA | 7.5x12.5mm | Lead free & Halogen free | 667/800/1066 | Now |
| 512Mb | 128M x4 | K4T51043QJ-HC(E6/F7/E7) | 60-FBGA | 7.5x9.5mm | Lead free & Halogen free | 667/800 | Q3 |
| | 64M x8 | K4T51083QJ-HC(E6/F7/E7/F8) | 60-FBGA | 7.5x9.5mm | Lead free & Halogen free | 667/800/1066 | Q3 |
| | 32M x16 | K4T51163QJ-HC(E6/F7/E7/F8) | 84-FBGA | 7.5x12.5mm | Lead free & Halogen free | 667/800/1066 | Q3 |
| | 256M x4 | K4T1G044QF-BC(E6/F7/E7) | 68-FBGA | 7.5x9.5mm | Lead free & Halogen free | 667/800 | Now |
| 1Gb | 128M x8 | K4T1G084QF-BC(E6/F7/E7/F8) | 68-FBGA | 7.5x9.5mm | Lead free & Halogen free | 667/800/1066 | Now |
| | 64M x16 | K4T1G164QF-BC(E6/F7/E7/F8) | 84-FBGA | 7.5x12.5mm | Lead free & Halogen free | 667/800/1066 | Now |

NOTES: E6=DDR2-667 (5-5-5)

F7=DDR2-800 (6-6-6)

E7=DDR2-800 (5-5-5) F8=DDR2-1066 (7-7-7)

Voltage = 1.8V

DDR SDRAM 1U REGISTERED MODULES

| Density | Organization | Part Number | Composition | Speed (Mbps) |
|---------|--|------------------|-------------|--------------|
| 1GB | 128Mx72 | M312L2920GH3-CB3 | (128Mx4)*18 | 333/400 |
| 2GB | 256Mx72 | M312L5720GH3-CB3 | (128Mx4)*36 | 333/400 |
| NOTES: | B0 = DDR266 (133MHz @ CL=2.5) A2 = DDR266 (133MHz @ Cl=2) B3 = DDR333 (166MHz @ CL=2.5) CC = DDR400 (200MHz @ CL=3) | | | |

DDR DRAM SODIMM MODULES

Type: 184-pin

| Density | Organization | Part Number | Composition | Speed (Mbps) |
|---------|--|--------------------|--------------|--------------|
| 512MB | 64Mx64 | M470L6524GL0-CB300 | (32M x 16)*8 | 333 |
| NOTES: | B0 = DDR266 (133MHz @ CL=2.5) CC = DDR400 (200MHz @ CL=3) B3 = DDR333 (166MHz @ CL=2.5) A2 = DDR266 (133MHz @ Cl=2) | | | |

DDR SDRAM COMPONENTS

| Density | Organization | Part Number | # Pins - Package | Speed (Mbps) |
|---------|--------------|--------------------|------------------|--------------|
| | 64Mx4 | K4H560438N-LCB3/B0 | 66-TSOP | 266/333 |
| 256Mb | 32Mx8 | K4H560838N-LCCC/B3 | 66-TSOP | 333/400 |
| | 16Mx16 | K4H561638N-LCCC/B3 | 66-TSOP | 333/400 |
| | 128Mx4 | K4H510438G-LCB3/B0 | 66-TSOP | 266/333 |
| | 1 Z OIVIX 4 | K4H510438G-HCCC/B3 | 60-FBGA | 333/400 |
| 512Mb | 64Mx8 | K4H510838G-LCCC/B3 | 66-TSOP | 333/400 |
| | 04IVIXO | K4H510838G-HCCC/B3 | 60-FBGA | 333/400 |
| | 32Mx16 | K4H511638G-LCCC/B3 | 66-TSOP | 333/400 |
| 128Mb | 8Mx16 | K4H2816380-LCCC | 66-TSOP | 400 |

NOTES:

B0 = DDR266 (133MHz @ CL=2.5) A2 = DDR266 (133MHz @ Cl=2) B3 = DDR333 (166MHz @ CL=2.5)

CC = DDR400 (200MHz @ CL=3)

8

SDRAM COMPONENTS

| Density | Organization | Part Number | # Pins - Package | Speed (Mbps) | Refresh | Remarks |
|----------|--------------|----------------------------|------------------|--------------|---------|-------------------------|
| 64Mb | 8Mx8 | K4S640832N-LC75000 | 54-TSOP | 133 | 4K | EOL with no replacement |
| 04IVID | 4Mx16 | K4S641632N-LC(L)(75/60)000 | 54-TSOP | 133/166 | 4K | EOL with no replacement |
| 128Mb | 16Mx8 | K4S2808320-LC(L)75000 | 54-TSOP | 133 | 4K | |
| I ZOIVIU | 8Mx16 | K4S2816320-LC(L)(75/60)000 | 54-TSOP | 133/166 | 4K | |
| | 64Mx4 | K4S560432N-LC(L)75000 | 54-TSOP | 133 | 8K | |
| 256Mb | 32Mx8 | K4S560832N-LC(L)75000 | 54-TSOP | 133 | 8K | |
| | 16Mx16 | K4S561632N-LC(L)(75/60)000 | 54-TSOP | 133/166 | 8K | |
| | 128Mx4 | K4S510432D-UC(L)(75)000 | 54-TSOP | 133 | 8K | EOL with no replacement |
| 512Mb | 64Mx8 | K4S510832D-UC(L)(75)000 | 54-TSOP | 133 | 8K | EOL with no replacement |
| | 32Mx16 | K4S511632D-UC(L)(75)000 | 54-TSOP | 133 | 8K | EOL with no replacement |

NOTES: L = Commercial Temp., Low Power

For Industrial Temperature, check with SSI Marketing

Banks: 4

All products are Lead Free

Voltage: 3.3V

Speed: PC133 (133MHz CL=3/PC100 CL2)

RDRAM COMPONENTS

| Density | Organization | Part Number | Speed (Mbps) | # Pins-Package | Refresh | Note |
|---------|-----------------------|--------------------|--------------|----------------|----------|---------------|
| 288M | x18 | K4R881869I-DCT9000 | 1066 | 92-FBGA | 16K/32ms | EOL in Aug'10 |
| NOTES: | All products are lead | free | | | | |

GRAPHICS DRAM COMPONENTS

| Туре | Density | Organization | Part Number | Package | VDD/VDDQ | Speed Bin (MHz) | Status |
|-------|---------|--------------|------------------|-----------|------------|-------------------|----------------|
| GDDR5 | 1Gb | 32Mx32 | K4G10325FE-HC(1) | 170-FBGA | 1.5/1.5V | 1800/2000/2500 | |
| | 1Gb | 32Mx32 | K4J10324KE-HC(1) | 136-FBGA | 1.8V/1.8V | 700/800/1000/1200 | |
| CDDDO | | | K4J52324QH-HC(1) | 136-FBGA | 1.8/1.8V | 700/800 | EOL Mar '10 |
| GDDR3 | 512Mb | 16Mx32 | K4J52324QH-HJ(1) | 136-FBGA | 1.9/1.9V | 1000 | EOL Mar '10 |
| | | | K4J52324QH-HJ(1) | 136-FBGA | 2.05/2.05V | 1200 | EOL Mar '10 |
| GDDR2 | 1Gb | 64Mx16 | K4N1G164QE-HC(1) | 84-FBGA | 1.8/1.8V | 400/500 | EOL Mar '10 |
| GDDRZ | 512Mb | 32Mx16 | K4N51163QG-HC(1) | 84-FBGA | 1.8/1.8V | 400/500 | EOL Mar '10 |
| | | 414420 | K4D263238K-VC(1) | 144-FBGA | 2.5/2.5V | 200/250 | CuSmpl Oct '09 |
| GDDR1 | 128Mb | 4Mx32 | K4D263238K-UC(1) | 100-TQFP | 2.5/2.5V | 200/250 | |
| | | 8Mx16 | K4D261638K-LC(1) | 66-TSOPII | 2.5/2.5V | 200/250 | EOL Sep '10 |

NOTES: Package:

Q: TQFP

U: TQFP (Lead Free)

G: 84/144 FBGA

V: 144 FBGA (Lead Free)

Z: 84 FBGA (Lead Free)

T: TSOP L: TSOP (Lead Free)

A: 136 FBGA

B: 136 FBGA (Lead Free)

H: FBGA (Halogen Free & Lead Free) E: 100 FBGA (Halogen Free & Lead Free) (1) Speeds (clock cycle - speed bin):

04: 0.4ns (2500MHz) 05: 0.5ns (2000MHz)

5C: 0.555 (1800MHz)

07: 0.71ns (1400MHz) 08: 0.83ns (1200MHz) 09: 0.90ns (1100MHz)

1A: 1ns (1000MHz) 11: 1.1ns (900MHz) 12: 1.25ns (800MHz)

20: 2.0ns (500MHz)

22: 2.2ns (450MHz) 25: 2.5ns (400MHz) 2A: 2.86ns (350MHz) 14: 1.429ns (700MHz) 33: 3.3ns (300MHz) 16: 1.667ns (600MHz) 40: 4.0ns (240MHz)

50: 5.0ns (200MHz)

MOBILE-SDR/DDR

| Density | Туре | Organization | Part Number | Package | Power | Production |
|---------|--------|-----------------|------------------|--------------------------|-------|------------|
| | MSDR | 16Mx16 | K4M56163PN-BG(1) | 54-FBGA | 1.8V | Now |
| 256Mb | INIONU | 8Mx32 | K4M56323PN-HG(1) | 90-FBGA | 1.8V | Now |
| ZJOIVID | MDDR | 16Mx16 | K4X56163PN-FG(1) | 60-FBGA | 1.8V | Now |
| | MDDK | 8Mx32 | K4X56323PN-8G(1) | 90-FBGA | 1.8V | Now |
| | MSDR | 32Mx16 | K4M51163PI-BG(1) | 54-FBGA | 1.8V | Now |
| 512Mb | IVIOUT | 16Mx32 | K4M51323PI-HG(1) | 90-FBGA | 1.8V | Now |
| JIZIVID | MDDR | 32Mx16 | K4X51163PI-FG(1) | 60-FBGA | 1.8V | Now |
| | IVIDUN | 16Mx32 | K4X51323PI-8G(1) | 90-FBGA | 1.8V | Now |
| | | 64Mx16 | K4X1G163PE-FG(1) | 60-FBGA | 1.8V | Now |
| 1Gb | MDDR | 32Mx32 | K4X1G323PE-8G(1) | 90-FBGA | 1.8V | Now |
| TGD | INIDUR | 64Mx16 | K4X1G163PF-FG(1) | 60-FBGA | 1.8V | MP Q1'11 |
| | | 32Mx32 | K4X1G323PF-8G(1) | 90-FBGA | 1.8V | MP Q1'11 |
| 2Gb | MDDR | 128Mx16 | K4X2G163PC-FG(1) | 60-FBGA | 1.8V | Now |
| 200 | INIDUN | 64Mx32 | K4X2G323PC-8G(1) | 90-FBGA | 1.8V | Now |
| | | x32 (2CS, 2CKE) | K4X4G303PB-AG(1) | 168-FBGA, 12x12 PoP, DDP | 1.8V | Now |
| 4Gb | MDDR | x32 (2CS, 2CKE) | K4X4G303PB-AG(1) | 168-FBGA, 12x12 PoP, DDP | 1.8V | Now |
| | | x32 (2CS, 2CKE) | K4X4G303PB-7G(1) | 240-FBGA, 14x14 PoP, DDP | 1.8V | Now |

LPDDR2

| Density | Туре | Organization | Part Number | Package | Power | Production |
|---------|--------|--------------|------------------|--------------------------|-------|------------|
| 512Mb | LPDDR2 | 1CH x32 | K4P51323EI-AG(1) | 168-FBGA, 12x12 PoP | 1.8V | Now |
| 1Gb | LPDDR2 | 1CH x32 | K4P1G324EE-AG(1) | 168-FBGA, 12x12 PoP | 1.2V | Now |
| | | 1CH x32 | K4P2G324EC-AG(1) | 168-FBGA, 12x12 PoP | 1.2V | Now |
| 2Gb | LPDDR2 | 2CH x32/ch | K3PE3E300M-XG(1) | 216-FBGA, 12x12 PoP | 1.2V | Now |
| | | | K3PE3E300A-XG(1) | 240-FBGA, 14x14 PoP | 1.2V | Now |
| | | 1CH x32 | K4P4G304EC-AG(1) | 168-FBGA, 12x12 PoP, DDP | 1.2V | Now |
| 4Gb | LPDDR2 | | K3PE4E400M-XG(1) | 216-FBGA, 12x12 PoP, DDP | 1.2V | Now |
| 460 | LFUUNZ | 2CH x32/ch | K3PE4E400M-XG(1) | 216-FBGA, 12x12 PoP, DDP | 1.2V | Now |
| | | | K3PE4E400A-XG(1) | 240-FBGA, 14x14 PoP, DDP | 1.2V | Now |

NOTES: All products offered at Extended, Low, i-TCSR & PASR & DS (Temp, Power) (1) Speed:

Mobile-SDR 60: 166MHz, CL3 75: 133MHz, CL3

Mobile-DDR D8: 200MHz, CL3 C6: 166MHz, CL3

LPDDR2

C0: 667Mbps C1: 800Mbps

| 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 |
|---|----------------|---------|--------------|--------------------------------|--------------------------|----|---|-------|--------------|---|
| K | 4 | T | XX | XX | Х | Х | Х | Х | Х | XX |
| | | | | | | | | | | |
| SAMSUNG Memory | | | | | | | | | | Spee |
| DRAM | | | | | | | | | | Temp & Power |
| DRAM Type | | | | | | | | | | Package Typ Revisio |
| Density | | | | | | | | | | Interface (VDD, VDD) |
| Bit Organization | | | | | | | | | | Number of Internal Bank |
| 1. Memory (K) | | | 08: | x8 | | | | 9. Pa | ckage Ty | pe |
| 2. DRAM: 4 | | | 15:: 16:: | x16 (2CS) x16 | | | | DD | R SDRAM | |
| 3. DRAM Type | | | | , | DEC Standa DEC Standa | , | | | | d-free & Halogen-free) -free & Halogen-free) |
| B: DDR3 SDRAM | | | | x32 (2CS, 2 | | / | | F: I | FBGA for 64 | Mb DDR (Lead-free & Halogen-f |
| D: GDDR SDRAM | | | | x32 (2CS) | , | | | 6: | sTSOP II (Le | ad-free & Halogen-free) |
| G: GDDR5 SDRAM | | | 32:: | x32 | | | | T: 1 | TSOP II | |
| H: DDR SDRAM | | | 6. # 0 | f Internal | Banks | | | | sTSOP II | |
| J: GDDR3 SDRAM | | | | | | | | | FBGA | d for a |
| M: Mobile SDRAM | | | | Banks | | | | | TSOP II (Lea | , |
| N: SDDR2 SDRAM | | | | Banks | | | | | sTSOP II (Le | • |
| S: SDRAM | | | | Banks | | | | Z: | FBGA (Lead | -tree) |
| T: DDR SDRAM | | | 5: 1 | 6 Banks | | | | DD | R2 SDRAN | 1 |
| U: GDDR4 SDRAM | | | 7. Inte | rface (VI | DD, VDDC | !) | | Z: | FBGA (Lead | -free) |
| V: Mobile DDR SDRAM Pow | er Efficient A | Address | 2.11 | /TTL, 3.3V, 3 | 3 31/ | | | J: I | FBGA DDP (| Lead-free) |
| W: SDDR3 SDRAM | | | | /TTL, 3.5V, 2 /TTL, 2.5V, 2 | | | | Q: | FBGA QDP | (Lead-free) |
| X: Mobile DDR SDRAM | | | | STL-2 1.8V, | | | | H: | FBGA (Lead | -free & Halogen-free) |
| Y: XDR DRAM | | | | STL-2 1.6V, STL-15 1.5\ | | | | M: | FBGA DDP | (Lead-free & Halogen-free) |
| Z: Value Added DRAM | | | | STL-2, 2.5V | | | | | | Lead-free & Halogen-free) |
| 4. Density | | | | STL, 2.5V, 1 | | | | T: F | FBGA DSP (I | _ead-free & Halogen-free, Thin) |
| | | | | OD-15 (1.5\ | | | | DD | R3 SDRAN | 1 |
| 10: 1G, 8K/32ms | | | | STL_2 DLL, | | | | Z: | FBGA (Lead | -free) |
| 16: 16M, 4K/64ms | | | | VTTL, 1.8V, | | | | H: | FBGA (Halog | gen-free & Lead-free) |
| 26: 128M, 4K/32ms | | | | VTTL, 1.5V, | | | | Gr | aphics Mei | morv |
| 28: 128M, 4K/64ms | | | | /TTL, 1.8V, | | | | | TQFP | , |
| 32: 32M, 2K/32ms | | | | STL-2 1.8V, | | | | | TQFP (Lead | Free) |
| 50: 512M, 32K/16ms 51: 512M, 8K/64ms | | | | STL-2, 2.8V | | | | | 84/144 FB0 | |
| 52: 512M, 8K/32ms | | | U: D | RSL, 1.8V, 1 | .2V | | | V: | 144 FBGA (I | Lead Free) |
| 54: 256M, 16K/16ms | | | 8. Rev | | | | | | 84 FBGA(Le | |
| 55: 256M, 4K/32ms | | | O. HEV | 131011 | | | | T: 1 | TSOP | |
| 56: 256M, 8K/64ms | | | | nd Generation | | | | L: | TSOP (Lead | Free) |
| 62: 64M, 2K/16ms | | | | rd Generatio | | | | A: | 136 FBGA | |
| 64: 64M, 4K/64ms | | | | th Generatio | | | | B: | 136 FBGA(L | .ead Free) |
| 68: 768M, 8K/64ms | | | | th Generatio | | | | H: | FBGA(Holog | en Free & Lead Free) |
| 1G: 1G, 8K/64ms | | | | th Generatio | | | | E: | 100 FBGA(H | lologen Free & Lead Free) |
| 2G: 2G, 8K/64ms | | | | th Generatio | | | | SD | RAM | |
| 4G: 4G, 8K/64ms | | | | th Generatio | | | | | | d-free & Halogen-free) |
| | | | | th Generatio | | | | | STSOP II | . |
| 5. Bit Organization | | | | oth Generation | | | | | TSOP II | |
| 02: x2 | | | | 1th Generati | | | | | TSOP II (Lea | id-free) |
| 04: x4 | | | | 2th Generati | | | | | sTSOP II (Le | , |
| 06: x4 Stack (Flexframe) | | | | st Generatio | | | | | (| , |
| 07: v0 Ctook (Elayframa) | | | N: 1 | 4th Generat | ion | | | | | |

Q: 17th Generation

2H 2010

07: x8 Stack (Flexframe)

www.samsung.com/semi/dram

COMPONENT DRAM ORDERING INFORMATION

| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | |
|------------------|---|---|---|----|----|---|---|---|---|----|--------|-------------------|
| | K | 4 | T | XX | XX | X | Х | Х | X | X | XX | |
| | | | | | | | | | | | | |
| SAMSUNG Memory | | | | | | | | | | | | Speed |
| DRAM | | | | | | | | | | | | |
| DRAM Type | | | | | | | | | | | | Package Type |
| Density | | | | | | | | | | | | Revision |
| | | | | | | | | | | | | face (VDD, VDDQ) |
| Bit Organization | | | | | | | | | | | Number | of Internal Banks |

XDR DRAM

J: BOC(LF) P: BOC

Mobile DRAM

Leaded / Lead Free

G/A: 52balls FBGA Mono

R/B: 54balls FBGA Mono

X /Z: 54balls BOC Mono

J N: 60(72)balls FBGA Mono 0.5pitch

L /F: 60balls FBGA Mono 0.8pitch

S/D: 90balls FBGA

Monolithic (11mm x 13mm)

F/H: Smaller 90balls FBGA Mono

Y/P: 54balls CSP DDP

M/E: 90balls FBGA DDP 10. Temp & Power - COMMON

(Temp, Power)

C: Commercial, Normal (0'C - 95'C) & Normal

C: (Mobile Only) Commercial (-25 ~ 70°C), Normal Power

J: Commercial, Medium

L: Commercial, Low (0'C - 95'C) & Low Power

L: (Mobile Only) Commercial, Low, i-TCSR

F: Commercial, Low, i-TCSR & PASR & DS

E: Extended (-25~85'C), Normal

N: Extended, Low, i-TCSR

G: Extended, Low, i-TCSR & PASR & DS

I: Industrial, Normal (-40'C - 85'C) & Normal Power

P: Industrial, Low (-40'C - 85'C) & Low Power

H: Industrial, Low, i-TCSR & PASR & DS

11. Speed (Wafer/Chip Biz/BGD: 00)

DDR SDRAM

CC: DDR400 (200MHz @ CL=3, tRCD=3, tRP=3)

B3: DDR333 (166MHz @ CL=2.5, tRCD=3. tRP=3) *1

A2: DDR266 (133MHz @ CL=2, tRCD=3, tRP=3)

B0: DDR266 (133MHz @ CL=2.5, tRCD=3, tRP=3

Note 1: "B3" has compatibility with "A2" and "B0"

DDR2 SDRAM

CC: DDR2-400 (200MHz @ CL=3, tRCD=3, tRP=3)

D5: DDR2-533 (266MHz @ CL=4, tRCD=4, tRP=4)

E6: DDR2-667 (333MHz @ CL=5, tRCD=5, tRP=5

F7: DDR2-800 (400MHz @ CL=6, tRCD=6, tRP=6

E7: DDR2-800 (400MHz @ CL=5, tRCD=5, tRP=5)

DDR3 SDRAM

F7: DDR3-800 (400MHz @ CL=6, tRCD=6,

F8: DDR3-1066 (533MHz @ CL=7, tRCD=7, tRP=7

G8: DDR3-1066 (533MHz @ CL=8, tRCD=8, tRP=8

H9: DDR3-1333 (667MHz @ CL=9, tRCD=9, tRP=9

K0: DDR3-1600 (800MHz @ CL=11, tRCD=11, tRP=11)

Graphics Memory

18: 1.8ns (550MHz)

04: 0.4ns (2500MHz)

20: 2.0ns (500MHz)

05: 0.5ns (2000MHz)

22: 2.2ns (450MHz)

5C: 0.56ns (1800MHz)

25: 2.5ns (400MHz)

06: 0.62ns (1600MHz)

2C: 2.66ns (375MHz)

6A: 0.66ns (1500MHz)

2A: 2.86ns (350MHz)

07: 0.71ns (1400MHz)

33: 3.3ns (300MHz)

7A: 0.77ns (1300MHz)

36: 3.6ns (275MHz)

08: 0.8ns (1200MHz)

40: 4.0ns (250MHz)

09: 0.9ns (1100MHz)

45: 4.5ns (222MHz)

1: 1.0ns (1000MHz)

50/5A: 5.0ns (200MHz)

1:1.1ns (900MHz)

55: 5.5ns (183MHz)

12: 1.25ns (800MHz)

60: 6.0ns (166MHz)

14: 1.4ns (700MHz)

16: 1.6ns (600MHz)

SDRAM (Default CL=3)

50: 5.0ns (200MHz CL=3)

60: 6.0ns (166MHz CL=3)

67: 6.7ns

75: 7.5ns PC133 (133MHz CL=3)

XDR DRAM

A2: 2.4Gbps, 36ns, 16Cycles

B3: 3.2Gbps, 35ns, 20Cycles

C3: 3.2Gbps, 35ns, 24Cycles

C4: 4.0Gbps, 28ns, 24Cycles

DS: Daisychain Sample

Mobile-SDRAM

60: 166MHz, CL 3

75: 133MHz, CL 3

80: 125MHz. CL 3

1H: 105MHz, CL 2 1L: 105MHz, CL 3

15: 66MHz, CL 2 & 3

Mobile-DDR

C3: 133MHz, CL 3

C2: 100MHz, CL 3

C0: 66MHz, CL 3

Note: All of Lead-free or Halogen-free product are in compliance with RoHS

12

MODULE DRAM ORDERING INFORMATION

| | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | |
|---|----|------|--------|-----------|-------------|---------------|-----------------|---|---|---|---|------------------|
| Х | XX | Т | XX | Х | Х | Х | Х | Х | Х | XX | Х | |
| | | | | | | | | | | | | AMB Vendor |
| | | | | | | | | | | | | Speed |
| | | | | | | | | | | | | |
| | | | | | | | | | | | | PCB Revision |
| | | | | | | | | | | | | Package |
| | | | | | | | | | | | Cor | nponent Revision |
| | | | | | | | | | | | | |
| | X | X XX | X XX T | X XX T XX | X XX T XX X | X XX T XX X X | X XX T XX X X X | X XX T XX X X X X X X X X X X X X X X X | X XX T XX X X X X X X X X X X X X X X X | X XX T XX X X X X X X X X X X X X X X X | X XX T XX X X X X X X X X X X X X X X X | |

1. Memory Module: M

2. DIMM Type

3: DIMM

4: SODIMM

3. Data bits

12: x72 184pin Low Profile Registered DIMM

63: x63 PC100 / PC133 μ SODIMM with SPD for 144pin

64: x64 PC100 / PC133 SODIMM with SPD for 144pin (Intel/JEDEC)

66: x64 Unbuffered DIMM with SPD for 144pin/168pin (Intel/JEDEC)

68: x64 184pin Unbuffered DIMM

70: x64 200pin Unbuffered SODIMM

71: x64 204pin Unbuffered SODIMM

74: x72 /ECC Unbuffered DIMM with SPD for 168pin (Intel/JEDEC)

77: x72 /ECC PLL + Register DIMM with SPD for 168pin (Intel PC100)

78: x64 240pin Unbuffered DIMM

81: x72 184pin ECC unbuffered DIMM

83: x72 184pin Registered DIMM

90: x72 /ECC PLL + Register DIMM

91: x72 240pin ECC unbuffered DIMM

92: x72 240pin VLP Registered DIMM

93: x72 240pin Registered DIMM

95: x72 240pin Fully Buffered DIMM with SPD for 168pin (JEDEC PC133)

4. DRAM Component Type

B: DDR3 SDRAM (1.5V VDD)

L: DDR SDRAM (2.5V VDD)

S: SDRAM

T: DDR2 SDRAM (1.8V VDD)

www.samsung.com/semi/dram

5. Depth

09: 8M (for 128Mb/512Mb)

17: 16M (for 128Mb/512Mb)

16: 16M

28: 128M

29: 128M (for 128Mb/512Mb)

32: 32M

33: 32M (for 128Mb/512Mb)

51: 512M

52: 512M (for 512Mb/2Gb)

56: 256M

57: 256M (for 512Mb/2Gb)

59: 256M (for 128Mb/512Mb)

64: 64M

65: 64M (for 128Mb/512Mb)

1G: 1G

1K: 1G (for 2Gb)

6. # of Banks in Comp. & Interface

1: 4K/64mxRef., 4Banks & SSTL-2

2:8K/64ms Ref., 4Banks & SSTL-2

2: 4K/ 64ms Ref., 4Banks & LVTTL (SDR Only)

5: 8K/ 64ms Ref., 4Banks & LVTTL (SDR Only)

5: 4Banks & SSTL-1.8V

6: 8Banks & SSTL-1.8V

7. Bit Organization

0: x 4

3: x 8

4: x16

6: x 4 Stack (JEDEC Standard)

7: x 8 Stack (JEDEC Standard)

8: x 4 Stack

9: x 8 Stack

8. Component Revision

A: 2nd Gen.

B: 3rd Gen.

C: 4th Gen.

D: 5th Gen.

E: 6th Gen.

F: 7th Gen.

G: 8th Gen.

M: 1st Gen.

Q: 17th Gen.

2H 2010

9. Package

E: FBGA QDP (Lead-free & Halogen-free)

G: FBGA

H: FBGA (Lead-free & Halogen-free)

J: FBGA DDP (Lead-free)

M: FBGA DDP (Lead-free & Halogen-free)

N: sTSOP

Q: FBGA QDP (Lead-free)

T: TSOP II (400mil)

U: TSOP II (Lead-Free)

V: sTSOP II (Lead-Free)

Z: FBGA(Lead-free)

10. PCB Revision

0: Mother PCB

1: 1st Rev

2: 2nd Rev.

3: 3rd Rev. 4: 4th Rev.

A: Parity DIMM

S: Reduced PCB

3. Neudoed I OD

U: Low Profile DIMM

11. Temp & Power

C: Commercial Temp. (0°C ~ 95°C) & Normal Power

L: Commercial Temp. (0°C ~ 95°C) & Low Power

12. Speed

CC: (200MHz @ CL=3, tRCD=3, tRP=3)

D5: (266MHz @ CL=4, tRCD=4, tRP=4) E6: (333MHz @ CL=5, tRCD=5, tRP=5)

F7: (400MHz @ CL=6, tRCD=6, tRP=6)

E7: (400MHz @ CL=5, tRCD=5, tRP=5)

F8: (533MHz @ CL=7, tRCD=7, tRP=7)

10. (333)VIII 2 @ GL=7, (11GD=7, (11I =7)

G8: (533MHz @ CL=8, tRCD=8, tRP=8)

H9: (667MHz @ CL=9, tRCD=9, tRP=9)

K0: (800MHz @ CL=10, tRCD=10, tRP=10)

7A: (133MHz CL=3/PC100 CL2)

13. AMB Vendor for FBDIMM

0. 5: Intel

1, 6, 8: IDT

9: Montage

Note: All of Lead-free or Halogen-free product are in compliance with RoHS

13

DRAM Ordering Information

SLC FLASH

| | | | | | | | MOQ | |
|----------------------------|-----------------|-----------------|-----------------|----------|--------|----------|----------|--------|
| amily | Density | Part Number | Package Type | Org. | Vol(V) | Tray | T/R | Status |
| | | I | | | | -xxxx0xx | -xxx0Txx | |
| | 16Gb Mono | K9FAG08U0M-HCB0 | BGA | X8 | 3.3 | 960 | 1000 | E/S |
| | | K9FAG08S0M-HCB0 | BGA | X8 | 1.8 | 960 | 1000 | E/S |
| | 32Gb DDP | K9KBG08U1M-HCB0 | BGA | X8 | 3.3 | 960 | 1000 | E/S |
| 6Gb Based | | K9KBG08S1M-HCB0 | BGA | X8 | 1.8 | 960 | 1000 | E/S |
| | 64Gb QDP | K9WCG08U5M-HCB0 | BGA | X8 | 3.3 | 960 | 1000 | E/S |
| | | K9WCG08S5M-HCB0 | BGA | X8 | 1.8 | 960 | 1000 | E/S |
| | 128Gb ODP | K9QDG08U5M-HCB0 | BGA | X8 | 3.3 | 960 | 1000 | E/S |
| | | K9QDG08S5M-HCB0 | BGA | X8 | 1.8 | 960 | 1000 | E/S |
| | 64Gb DSP | K9NCG08U5M-PCK0 | TSOP1 | x8 | 3.3 | 960 | 1000 | M/P |
| | 32Gb QDP | K9WBG08U1M-PCB0 | TSOP1 | x8 | 3.3 | 960 | 1000 | M/P |
| OEGD GDI | OZOD QDI | K9WBG08U1M-PIB0 | TSOP1 | 8x | 3.3 | 960 | 1000 | M/P |
| Gb Based | 16Gb DDP | K9KAG08U0M-PCB0 | TSOP1 | 8x | 3.3 | 960 | 1000 | M/P |
| | TOGD DDI | K9KAG08U0M-PIB0 | TSOP1 | x8 | 3.3 | 960 | 1000 | M/P |
| | 8Gb Mono | K9F8G08U0M-PCB0 | TS0P1 | x8 | 3.3 | 960 | 1000 | M/P |
| | OUD WIDHU | K9F8G08U0M-PIB0 | TS0P1 | x8 | 3.3 | 960 | 1000 | M/P |
| | K9WAG08U1D-SCB0 | TSOP1 HF&LF | х8 | 3.3 | 960 | 1000 | C/S | |
| 16Gb QDP Gb Based 8Gb DDP | | K9WAG08U1D-SIB0 | TSOP1 HF&LF | x8 | 3.3 | 960 | 1000 | C/S |
| | 16Gb QDP | K9WAG08U1B-PCB0 | TSOP1 | x8 | 3.3 | 960 | 1000 | M/P |
| | | K9WAG08U1B-PIB0 | TSOP1 | x8 | 3.3 | 960 | 1000 | M/P |
| | | K9WAG08U1B-KIB0 | ULGA HF & LF | x8 | 3.3 | 960 | 2000 | M/P |
| | | K9K8G08U0D-SCB0 | TSOP1 HF&LF | X8 | 3.3 | 960 | 1000 | C/S |
| | | K9K8G08U0D-SIB0 | TSOP1 HF&LF | x8 | 3.3 | 960 | 1000 | C/S |
| | 8Gb DDP | K9K8G08U0B-PCB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P |
| | | K9K8G08U0B-PIB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P |
| | | K9K8G08U1B-KIB0 | ULGA HF & LF | х8 | 3.3 | 960 | 2000 | M/P |
| | | K9F4G08U0D-SCB0 | TSOP1 HF & LF | х8 | 3.3 | 960 | 1000 | C/S |
| | | K9F4G08U0D-SIB0 | TSOP1 HF& LF | X8 | 3.3 | 960 | 1000 | C/S |
| | 4Gb Mono | K9F4G08U0B-PCB0 | TS0P1 | х8 | 3.3 | 960 | 1000 | M/P |
| | | K9F4G08U0B-PIB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P |
| | | K9F4G08U0B-KIB0 | ULGA HF & LF | х8 | 3.3 | 960 | 2000 | M/P |
| | | K9F2G08U0C-SCB0 | TSOP-LF/HF | х8 | 3.3 | 960 | 1000 | C/S |
| | | K9F2G08U0C-SIB0 | TSOP-LF/HF | х8 | 3.3 | 960 | 1000 | C/S |
| Gb Based | 2Gb Mono | K9F2G08U0B-PCB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P |
| | | K9F2G08U0B-PIB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P |
| | | K9F1G08U0D-SCB0 | TSOP-LF/HF | х8 | 3.3 | 960 | 1000 | C/S |
| | | K9F1G08U0D-SIB0 | TSOP-LF/HF | х8 | 3.3 | 960 | 1000 | C/S |
| Gb Based | 1Gb Mono | K9F1G08U0C-PCB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P |
| | | K9F1G08U0C-PIB0 | TSOP1 | хо х8 | 3.3 | 960 | 1000 | M/P |
| | | K9F1208U0C-PCB0 | TSOP1 | хо х8 | 3.3 | 960 | 1000 | M/P |
| | | | TSOP1 | | | 960 | | M/P |
| 12Mb Based | 512Mb Mono | K9F1208U0C-PIB0 | | x8 | 3.3 | | 1000 | |
| | | K9F1208R0C-JIB0 | 63 FBGA(8.5x13) | х8 | 1.8 | 1120 | - | M/P |
| | | K9F1208U0C-JIB0 | 63 FBGA(8.5x13) | х8 | 3.3 | 1120 | - | M/P |
| | | K9F5608U0D-PCB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P |
| 56Mb Based | 256Mb Mono | K9F5608U0D-PIB0 | TSOP1 | х8 | 3.3 | 1000 | 1000 | M/P |
| | | K9F5608R0D-JIB0 | 63 FBGA(9x11) | x8 | 1.8 | 1280 | 2000 | M/P |
| | | K9F5608U0D-JIB0 | 63 FBGA(9x11) | х8 | 3.3 | 1280 | 2000 | M/P |

Please contact your local Samsung sales representative for latest product offerings.

Note: All parts are lead free

MLC FLASH

| | | | | | | | | M | OQ D | |
|------|-----------------|-----------|------------|--------------------|---------------------------------|------|--------|-----------|----------|----------------------|
| Туре | Family | Density | Technology | Part Number | Package Type | Org. | Vol(V) | Tray | T/R | Comments |
| | | | | | .,,,,, | | | -ххххх0хх | -xxx0Txx | |
| | | 32Gb Mono | 27nm | K9HDG08U1A-SCB0 | TSOP - Lead free & Halogen free | x8 | 3.3 | 960 | 1000 | |
| | 32Gb Based | 64Gb DDP | 27nm | K9LCG08U0A-SCB0 | TSOP - Lead free & Halogen free | x8 | 3.3 | 960 | 1000 | |
| | | 128Gb QDP | 27nm | K9GBG08U0A-SCB0 | TSOP - Lead free & Halogen free | x8 | 3.3 | 960 | 1000 | |
| 2bit | | 16Gb Mono | 32nm | K9GAG08U0E-SCB0 | TSOP - Lead free & Halogen free | x8 | 3.3 | 960 | 1000 | |
| | 16Gb Based | 32Gb DDP | 32nm | K9LBG08U0E-SCB0 | TSOP - Lead free & Halogen free | x8 | 3.3 | 960 | 1000 | |
| | | 64Gb QDP | 32nm | K9HCG08U1E-SCB0 | TSOP - Lead free & Halogen free | х8 | 3.3 | 960 | 1000 | |
| | 8Gb Based | 8Gb Mono | 32nm | K9G8G08U0C-SCB0 | TSOP - Lead free & Halogen free | х8 | 3.3 | 960 | 1000 | |
| | | 32Gb mono | 32nm | K9CDG08U5A-MCB0001 | LGA - Lead free & Halogen free | x8 | 3.3 | 840 | - | Moving to 2xnm Q3'10 |
| 3bit | 3bit 32Gb Based | 64Gb DDP | 32nm | K9BCG08U1A-MCB0001 | LGA - Lead free & Halogen free | x8 | 3.3 | 840 | - | Moving to 2xnm Q3'10 |
| | | 128Gb QDP | 32nm | K9ABG08U0A-MCB0001 | LGA - Lead free & Halogen free | х8 | 3.3 | 840 | - | Moving to 2xnm Q3'10 |

Please contact your local Samsung sales representative for latest product offerings. Note: All parts are lead free

SD and MicroSD FLASH CARDS

| Application | Density | Controller | | | | | | |
|--------------|--------------------|---|--|--|--|--|--|--|
| | 2GB | | | | | | | |
| CD Cond | 4GB | Control vary local Company was far availability and avalating information | | | | | | |
| SD Card | 8GB 16GB 2GB | Contact your local Samsung rep for availability and ordering information | | | | | | |
| | | | | | | | | |
| | | | | | | | | |
| | 4GB | | | | | | | |
| MicroSD Card | 8GB | Contact your local Samsung rep for availability and ordering information | | | | | | |
| | 16GB | | | | | | | |
| | 32GB | | | | | | | |

Please contact your local Samsung sales representative for latest product offerings.

Note: All parts are lead free

SOLID STATE DRIVES (SSD)

| Interface | Size | Connector | Controller | Comp. | Capacity | Part Number |
|------------------|---------------------------------|-----------|------------------|---------------------------|--------------------|--------------------|
| | | | | | 64GB | MZ5PA064HMCD-0A000 |
| CATA II (Notivo) | SATA II (Native) 2.5" Thin SATA | Thin CATA | MAX | 16Gb | 128GB | MZ5PA128HMCD-0A000 |
| SAIA II (Nalive) | | | | 256GB | MZ5PA256HMDR-0A000 | |
| | | | TMDDR Controller | 32Gb Toggle-Mode DDR NAND | 512GB | Contact Sales |
| | | | | | 32GB | MZMPA032HMCD-00000 |
| SATA II (Native) | mSATA | mSATA | MAX | 16Gb | 64GB | MZMPA064HMDR-00000 |
| | | | | | 128GB | MZMPA128HMFU-00000 |

Please contact your local Samsung sales representative for latest product offerings.

Note: All parts are lead free

FLASH PRODUCT ORDERING INFORMATION



NtRAM

| Туре | Density | Organization | Part Number | Package | Operating Mode | Vdd (V) | Access Time tCD (ns) | Speed tCYC (MHz) | I/O Voltage (V) | Production Status |
|------------|---------|--------------|----------------|-------------------|-------------------|------------|-------------------------|---------------------|--------------------|----------------------|
| | 70Mb | 2Mx36 | K7N643645M | 100-TQFP, 165FBGA | SPB | 2.5 | 2.6, 3.5 | 250, 167 | 2.5 | Mass Production |
| | 72Mb | 4Mx18 | K7N641845M | 100-TQFP, 165FBGA | SPB | 2.5 | 2.6, 3.5 | 250, 167 | 2.5 | Mass Production |
| | | 1Mx36 | K7N323635C | 100-TQFP, 165FBGA | SPB | 3.3, 2.5 | 2.6, 3.5 | 250, 167 | 3.3, 2.5 | Mass Production |
| | 36Mb | 2Mx18 | K7N321835C | 100-TQFP, 165FBGA | SPB | 3.3, 2.5 | 2.6, 3.5 | 250, 167 | 3.3, 2.5 | Mass Production |
| | SOIVID | 1Mx36 | K7M323635C | 100-TQFP | FT | 3.3, 2.5 | 7.5 | 118 | 3.3, 2.5 | Mass Production |
| | | 2Mx18 | K7M321835C | 100-TQFP | FT | 3.3, 2.5 | 7.5 | 118 | 3.3, 2.5 | Mass Production |
| | | 1Mx18 | K7N161831B | 100-TQFP, 165FBGA | SPB | 3.3, 2.5 | 2.6, 3.5 | 250, 167 | 3.3, 2.5 | Mass Production |
| | 1 0 Mb | 512Kx36 | K7N163631B | 100-TQFP, 165FBGA | SPB | 3.3, 2.5 | 2.6, 3.5 | 250, 167 | 3.3, 2.5 | Mass Production |
| | 18Mb | 1Mx18 | K7M161835B | 100-TQFP | FT (SB) | 3.3 | 6.5 | 133 | 3.3, 2.5 | Mass Production |
| | | 512Kx36 | K7M163635B | 100-TQFP | FT (SB) | 3.3 | 6.5 | 133 | 3.3, 2.5 | Mass Production |
| NtRAM | | 256Kx36 | K7N803601B | 100-TQFP | SPB | 3.3 | 3.5 | 167 | 3.3,2.5 | Not for new designs |
| ININAIVI | | 512Kx18 | K7N801801B | 100-TQFP | SPB | 3.3 | 3.5 | 167 | 3.3,2.5 | Not for new designs |
| | | 256Kx36 | K7N803609B | 100-TQFP | SPB | 3.3 | 2.6 | 250 | 3.3,2.5 | Not for new designs |
| | | 512Kx18 | K7N801809B | 100-TQFP | SPB | 3.3 | 2.6 | 250 | 3.3,2.5 | Not for new designs |
| | 8Mb | 256Kx36 | K7N803645B | 100-TQFP | SPB | 2.5 | 3.5 | 167 | 2.5 | Not for new designs |
| | QIVID | 512Kx18 | K7N801845B | 100-TQFP | SPB | 2.5 | 3.5 | 167 | 2.5 | Not for new designs |
| | | 256Kx36 | K7N803649B | 100-TQFP | SPB | 2.5 | 2.6 | 250 | 2.5 | Not for new designs |
| | | 512Kx18 | K7N801849B | 100-TQFP | SPB | 2.5 | 2.6 | 250 | 2.5 | Not for new designs |
| | | 512Kx18 | K7M801825B | 100-TQFP | FT | 3.3 | 6.5 | 133 | 3.3, 2.5 | Not for new designs |
| | | 256Kx36 | K7M803625B | 100-TQFP | FT | 3.3 | 6.5 | 133 | 3.3, 2.5 | Not for new designs |
| | 4Mb | 128Kx36 | K7N403609B | 100-TQFP | SPB | 3.3 | 3 | 200 | 3.3,2.5 | Not for new designs |
| | 4Mb | 256Kx18 | K7N401809B | 100-TQFP | SPB | 3.3 | 3 | 200 | 3.3,2.5 | Not for new designs |
| SPB and FT | 4Mb | 256Kx18 | K7B401825B | 100-TQFP | SB | 3.3 | 6.5 | 133 | 3.3, 2.5 | Not for new designs |

NOTES: All TQFP products are lead free

NtRAM speed recommendations: For 200MHz use 250MHz; For 133MHz use 167MHz
NtRAM speed recommendation: Use 7.5ns Access Time use 6.5ns Access Time
Recommended SPB speeds are 250MHz and 167MHz Recommended SB Acess Speed is 7.5ns

Late-Write RR SRAM

| Density | Organization | Part Number | Package | Operating Mode | Vdd (V) | Access Time tCD (ns) | Speed tCYC (MHz) | I/O Voltage (V) | Production Status |
|---------|--------------|-------------|---------|-------------------|------------|-------------------------|---------------------|-----------------|-------------------|
| 32Mb | 1Mx36 | K7P323674C | 119-BGA | SP | 1.8 / 2.5V | 1.6, 2.0 | 300,250 | 1.5 (Max 1.8) | Mass Production |
| SZIVID | 2Mx18 | K7P321874C | 119-BGA | SP | 1.8 / 2.5V | 1.6, 2.0 | 300,250 | 1.5 (Max 1.8) | Mass Production |
| | 256Kx36 | K7P803611B | 119-BGA | SP | 3.3 | 1.6 | 300 | 1.5 (Max.2.0) | Mass Production |
| OMb | 512Kx18 | K7P801811B | 119-BGA | SP | 3.3 | 1.6 | 300 | 1.5 (Max.2.0) | Mass Production |
| 8Mb | 256Kx36 | K7P803666B | 119-BGA | SP | 2.5 | 2 | 250 | 1.5 (Max.2.0) | Mass Production |
| | 512Kx18 | K7P801866B | 119-BGA | SP | 2.5 | 2 | 250 | 1.5 (Max.2.0) | Mass Production |

DDR SYNCHRONOUS SRAM

| Туре | Density | Organization | Part Number | Package | Vdd (V) | Access Time tCD (ns) | Cycle Time (MHz) | I/O Voltage (V) | Production Status | Comments |
|----------------|---------|--------------|----------------|----------|------------|-------------------------|---------------------|--------------------|----------------------|---------------------------------------|
| | 16Mb | 512Kx36 | K7D163674B | 153-BGA | 1.8~2.5 | 2.3 | 330, 300 | 1.5~1.9 | Mass Production | |
| DDR | 16Mb | 1Mx18 | K7D161874B | 153-BGA | 1.8~2.5 | 2.3 | 330, 300 | 1.5~1.9 | Mass Production | |
| חחח | OMb | 256Kx36 | K7D803671B | 153-BGA | 2.5 | 1.7/1.9/2.1 | 333, 330, 250 | 1.5 (Max 2.0) | Not for new designs | |
| | 8Mb | 512Kx18 | K7D801871B | 153-BGA | 2.5 | 1.7/1.9/2.1 | 333, 330, 250 | 1.5 (Max 2.0) | Not for new designs | |
| | | | K7l641882M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-2B |
| | | 4Mx18 | K7l641884M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-4B |
| | 70Mb | | K7J641882M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | SIO-2B |
| | 72Mb | | K7l643682M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-2B |
| | | 2Mx36 | K7l643684M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-4B |
| | | | K7J643682M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | SIO-2B |
| | | | K7l321882C | 165-FBGA | 1.8 | 0.45 | 300,250 | 1.5,1.8 | Mass Production | CIO-2B |
| | | 2Mx18 | K7l321884C | 165-FBGA | 1.8 | 0.45 | 300,250 | 1.5,1.8 | Mass Production | CIO-4B |
| DDR | | | K7J321882C | 165-FBGA | 1.8 | 0.45 | 300,250 | 1.5,1.8 | Mass Production | SIO-2B |
| II CIO/ SIO | 36Mb | | K7l323682C | 165-FBGA | 1.8 | 0.45 | 300,250 | 1.5,1.8 | Mass Production | CIO-2B |
| | | 1Mx36 | K7l323684C | 165-FBGA | 1.8 | 0.45 | 300,250 | 1.5,1.8 | Mass Production | CIO-4B |
| | | | K7J323682C | 165-FBGA | 1.8 | 0.45 | 300,250 | 1.5,1.8 | Mass Production | SIO-2B |
| | | | K7l161882B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-2B |
| | | 1Mx18 | K7I161884B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-4B |
| | | | K7J161882B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | SIO-2B |
| | 18Mb | | K7J163682B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | SIO-2B |
| | | 512Kx36 | K7I163682B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-2B |
| | | | K7I163684B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-4B |
| | | 014.40 | K7K3218T2C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | DDRII + CIO-2B, 2 clocks latancy |
| | OOM In | 2Mx18 | K7K3218U2C | 165-FBGA | 1.8 | 0.45 | 400, 334 | 2.5 | Mass Production | DDRII + CIO-2B, 2.5 clocks latancy |
| | 36Mb | 1111/26 | K7K3236T2C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | DDRII + CIO-2B, 2 clocks latancy |
| DDR II+ | | 1Mx36 | K7K3236U2C | 165-FBGA | 1.8 | 0.45 | 400, 334 | 2.5 | Mass Production | DDRII + CIO-2B, 2.5 clocks latancy |
| CIO | | 184.40 | K7K1618T2C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | DDRII + CIO-2B, 2 clocks latancy |
| | 10Mh | 1Mx18 | K7K1618U2C | 165-FBGA | 1.8 | 0.45 | 400, 334 | 2.5 | Mass Production | DDRII + CIO-2B, 2.5 clocks latancy |
| | 18Mb | E1014-00 | K7K1636T2C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | DDRII + CIO-2B, 2 clocks latancy |
| | | 512Kx36 | K7K1636U2C | 165-FBGA | 1.8 | 0.45 | 400, 334 | 2.5 | Mass Production | DDRII + CIO-2B, 2.5 clocks latancy |

NOTES: 2B = Burst of 2 4B = Burst of 4 SIO = Separate I/O

CIO = Common I/O

For DDR II CIO/SIO: C-die use 330, 300, or 250MHz instad of 200MHz or 167MHz using a stable DLL circuit
For DDR II+ CIO: 2-clock latency is available. A 2.5-clock latency can be supported on 18Mb at 500Mhz and 36Mb at 450MHz

QDR SYNCHRONOUS SRAM

| Туре | Density | Organization | Part Number | Package | Vdd (V) | Access Time tCD (ns) | Cycle Time | I/O Voltage (V) | Production Status | Comments |
|---------|---------|--------------|----------------|----------|-------------|-------------------------|-----------------|--------------------|----------------------|---------------------------------------|
| | | 1Mx18 | K7Q161862B | 165-FBGA | 1.8v / 2.5v | 2.5 | 167 | 1.5,1.8 | Mass Production | QDR I - 2B |
| QDR I | 18Mb | TIVIXTO | K7Q161864B | 165-FBGA | 1.8v / 2.5v | 2.5 | 167 | 1.5,1.8 | Mass Production | QDR I - 4B |
| QUNT | TOIVID | 512Kx36 | K7Q163662B | 165-FBGA | 1.8v / 2.5v | 2.5 | 167 | 1.5,1.8 | Mass Production | QDR I - 2B |
| | | 312NX30 | K7Q163664B | 165-FBGA | 1.8v / 2.5v | 2.5 | 167 | 1.5,1.8 | Mass Production | QDR I - 4B |
| | | 8Mx9 | K7R640982M | 165-FBGA | 1.8 | 0.45,0.45,0.50 | 250,200,167 | 1.5,1.8 | Mass Production | QDR II-2B |
| | | 4Mx18 | K7R641882M | 165-FBGA | 1.8 | 0.45,0.45,0.50 | 250,200,167 | 1.5,1.8 | Mass Production | QDR II-2B |
| | 72Mb | 41013.10 | K7R641884M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | QDR II-4B |
| | | 2Mx36 | K7R643682M | 165-FBGA | 1.8 | 0.45,0.45,0.50 | 250,200,167 | 1.5,1.8 | Mass Production | QDR II-2B |
| | | ZIVIXOU | K7R643684M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | QDR II-4B |
| | | 4Mx9 | K7R320982C | 165-FBGA | 1.8 | 0.45 | 167, 250, 200 | 1.5,1.8 | Mass Production | QDR II-2B |
| | | 0Mv10 | K7R321882C | 165-FBGA | 1.8 | 0.45 | 167, 250, 200 | 1.5,1.8 | Mass Production | QDR II-2B |
| QDR II | 36Mb | 2Mx18 | K7R321884C | 165-FBGA | 1.8 | 0.45 | 200, 300, 250 | 1.5,1.8 | Mass Production | QDR II-4B |
| | | 114,00 | K7R323682C | 165-FBGA | 1.8 | 0.45 | 300, 250, 200 | 1.5,1.8 | Mass Production | QDR II-2B |
| | | 1Mx36 | K7R323684C | 165-FBGA | 1.8 | 0.45 | 200, 300, 250 | 1.5,1.8 | Mass Production | QDR II-4B |
| | 2Mx9 | 2Mx9 | K7R160982B | 165-FBGA | 1.8 | 0.45,0.45,0.50 | 250,200,167 | 1.5,1.8 | Mass Production | QDR II - 2B |
| | | 111110 | K7R161882B | 165-FBGA | 1.8 | 0.45,0.45,0.50 | 250,200,167 | 1.5,1.8 | Mass Production | QDR II - 2B |
| | 18Mb | 1Mx18 | K7R161884B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | QDR II - 4B |
| | | 512Kx36 | K7R163682B | 165-FBGA | 1.8 | 0.45,0.45,0.50 | 250,200,167 | 1.5,1.8 | Mass Production | QDR II - 2B |
| | | 312KX30 | K7R163684B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | QDR II - 4B |
| | | 411.00 | K7S3236T4C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | QDR II + 4B, 2 clocks latancy |
| | OCMA | 1Mx36 | K7S3236U4C | 165-FBGA | 1.8 | 0.45 | 400, 334 | 2.5 | Mass Production | QDR II + 4B, 2.5 clocks latancy |
| QDR II+ | 36Mb | QMv4.0 | K7S3218T4C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | QDR II + 4B, 2 clocks latancy |
| QDK II+ | | 2Mx18 | K7S3218U4C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | QDR II + 4B, 2.5 clocks latancy |
| | 4000 | 1Mx18 | K7S1618T4C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | QDR II + 4B, 2 clocks latancy |
| | 18Mb | 512Kx36 | K7S1636U4C | 165-FBGA | 1.8 | 0.45 400, 333 | | 1.5 | Mass Production | QDR II + 4B, 2.5 clocks latancy |

For QDR I, QDR II: 2B = Burst of 2, 4B = Burst of 4

For QDR II (36Mb): C-die use 300, 250MHz or 200MHz instead of 167MHz using a stable DLL circuit
For QDR II (72Mb): 2B = Burst of 2 and 250MHz or 200MHz is recommended, 4B = Burst of 4 and 300MHz or 250MHz is recommended
For QDR II+: 2-clock latency supported. 2.5-clock latency can be supported with 450MHz speed

SYNCHRONOUS SRAM ORDERING INFORMATION

| 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 | 15 | 16 | |
|----------------------|---|---|---|---|-------|----------|----------|----|----|----|----|----|---------|---------|---------|--------------------|
| K | 7 | Х | Х | Х | Х | Х | Х | X | Х | - | Х | Х | Х | Х | Х | |
| SAMSUNG Memory | | | | | | | | | | | | | | | | Packaging Type |
| Sync SRAM | | | | | | | | | | | | | | | | Speed |
| Small Classification | | | | | | | | | | | | | | | | Speed |
| Density | | | | | | | | | | | | | | | | Temp, Power |
| Density | | | | | | | | | | | | | | | | Package |
| Organization | | | | | | | | | | | | | | | | |
| Organization | | | | | | | | | | | | | | | | Generation |
| Vcc, Interface, Mode | | | | | | | | | | | | | | | | c, Interface, Mode |
| | | | | | | | | | | | | | | | | |
| 1. Memory (K) | | | | | 49: 2 | .5V,LVTT | L,Hi SPE | ED | | | | W | AFER, C | HIP BIZ | Level [| Division |

2. Sync SRAM: 7

3. Small Classification

- A: Sync Pipelined Burst
- B: Sync Burst
- D: Double Data Rate
- I: Double Data Rate II, Common I/O
- J: Double Data Rate, Separate I/O
- K: Double Data II+, Common I/O
- M: Sync Burst + NtRAM
- N: Sync Pipelined Burst + NtRAM
- P: Sync Pipe
- Q: Quad Data Rate I
- R: Quad Data Rate II
- S: Quad Data Rate II+

4~5. Density

| 80: 8M | 16: 18M |
|---------|---------|
| 40: 4M | 32: 36M |
| 64: 72M | |

6~7. Organization

| 08: x8 | 09: x9 |
|---------|---------|
| 18: x18 | 32: x32 |
| 36: x36 | |

8~9. Vcc, Interface, Mode

- 00: 3.3V,LVTTL,2E1D WIDE
- 01: 3.3V,LVTTL,2E2D WIDE
- 08: 3.3V,LVTTL,2E2D Hi SPEED
- 09: 3.3V,LVTTL,Hi SPEED
- 11: 3.3V, HSTL, R-R
- 12: 3.3V,HSTL,R-L
- 14: 3.3V,HSTL,R-R Fixed ZQ
- 22: 3.3V,LVTTL,R-R
- 23: 3.3V,LVTTL,R-L
- 25: 3.3V,LVTTL,SB-FT WIDE
- 30: 1.8/2.5/3.3V,LVTTL,2E1D
- 31: 1.8/2.5/3.3V,LVTTL,2E2D
- 35: 1.8/2.5/3.3V,LVTTL,SB-FT
- 44: 2.5V,LVTTL,2E1D
- 45: 2.5V,LVTTL,2E2D

- 52: 2.5V,1.5/1.8V,HSTL,Burst2
- 54: 2.5V,1.5/1.8V,HSTL,Burst4
- 62: 2.5V/1.8V,HSTL,Burst2
- 64: 2.5V/1.8V,HSTL,Burst4
- 66: 2.5V,HSTL,R-R
- 74: 1.8V,2.5V,HSTL,AII
- 82: 1.8V,HSTL,Burst2
- 84: 1.8V,HSTL,Burst4
- 88: 1.8V,HSTL,R-R
- T2: 1.8V,2Clock Latency,Burst2
- T4: 1.8V,2Clock Latency,Burst4
- U2: 1.8V,2.5Clock Latency,Burst2
- U4: 1.8V,2.5Clock Latency,Burst4

10. Generation

- M: 1st Generation
 - A: 2nd Generation
- B: 3rd Generation
- C: 4th Generation
- D: 5th Generation

11. "--"

12. Package

- H: BGA,FCBGA,PBGA
- G: BGA, FCBGA, FBGA (LF)
- F: FBGA
- E: FBGA (LF)
- Q: (L)QPF
- P: (L)QFP(LF)
- C: CHIP BIZ
- W: WAFER

13. Temp, Power

COMMON (Temp, Power)

- 0: NONE, NONE (Containing of error
- handling code)
- C: Commercial, Normal
- E: Extended.Normal
- I: Industrial, Normal

- 0: NONE.NONE
- 1: Hot DC sort
- 2: Hot DC, selected AC sort

14~15. Speed

Sync Burst, Sync Burst + NtRAM

- < Mode is R-L > (Clock Accesss Time) 65: 6.5ns 70: 7ns
- 75: 7.5ns 80: 8ns
- 85: 8.5ns

Other Small Classification (Clock Cycle Time)

- 10: 100MHz 11: 117MHz 13: 133MHz 14: 138MHz 16: 166MHz 20: 200MHz
- 25: 250MHz
- 26: 250MHz(1.75ns) 27: 275MHz 30: 300MHz 33: 333MHz 35: 350MHz 37: 375MHz 40: 400MHz(t-CYCLE) 42: 425MHz
- 45: 450MHz
- 50: 500MHz (except Sync Pipe)

16. Packing Type (16 digit)

- Common to all products, except of Mask ROM
- Divided into TAPE & REEL (In Mask ROM, divided into TRAY, AMMO packing separately)

| Туре | Packing Type | New Marking |
|------------|-------------------------|-------------|
| Component | TAPE & REEL | T |
| | Other (Tray, Tube, Jar) | 0 (Number) |
| | Stack | S |
| Component | TRAY | Υ |
| (Mask ROM) | AMMO PACKING | Α |
| Module | MODULE TAPE & REEL | Р |
| | MODULE Other Packing | M |
| | | |

SRAM Ordering Information

2H 2010

www.samsung.com/semi/sram

20

MCP: NAND/DRAM

| Memory | NAND Density | DRAM Density (Org.) | Voltages (NAND-DRAM) | MCP Package | PoP Package |
|-------------|--------------|---------------------|----------------------|-------------|-----------------|
| | | 256Mb (x16,x32) | 3.0V/1.8V - 1.8V | 107/137FBGA | 152FBGA |
| | 1Gb | 512Mb (x16,x32) | 2.7V/1.8V - 1.8V | 107/137FBGA | 119/152FBGA |
| NAND O DDAM | | 1Gb (x32) | 1.8V - 1.8V | 137FBGA | - |
| NAND & DRAM | 2Gb | 512Mb (x16,x32) | 1.8V - 1.8V | 107/137FBGA | 119/152FBGA |
| | 200 | 1Gb (x16,x32) | 1.8V - 1.8V | 107/137FBGA | 152/160/168FBGA |
| | 4Gb | 1Gb (x32) | 2.7V - 1.8V | 137FBGA | - |

MCP: OneNAND/DRAM

| Memory | OneNAND Density | DRAM Density (Org.) | Voltages (NAND-DRAM) | MCP Package | PoP Package |
|----------------|-----------------|---------------------|----------------------|-------------|-----------------|
| | E10Mb | 256Mb (x32) | 3.3V/1.8V - 1.8V | 188FBGA | 152FBGA |
| | 512Mb | 512Mb (x16,x32) | 1.8V - 1.8V | 167/202FBGA | 152FBGA |
| | 101 | 512Mb (x16,x32) | 1.8V - 1.8V | 167/202FBGA | 168FBGA |
| OneNAND & DDAM | 1Gb | 1Gb (x32) | 1.8V - 1.8V | - | 168FBGA |
| OneNAND & DRAM | | 512Mb (x16,x32) | 1.8V - 1.8V | - | 152/160/168FBGA |
| | 2Gb | 1Gb (x16,x32) | 1.8V - 1.8V | 167/202FBGA | 152/160/168FBGA |
| | | 2Gb (x32) | 1.8V - 1.8V | - | 152/168FBGA |
| | 4Gb | 1Gb (x16) | 1.8V - 1.8V | 202FBGA | - |

MCP: Flex-OneNAND/DRAM

| Memory | Flex-OneNAND Density | DRAM Density (Org.) | Voltages (NAND-DRAM) | MCP Package | PoP Package |
|------------------------|----------------------|---------------------|----------------------|-------------|-------------|
| Flex-OneNAND & DRAM | 8Gb | 2Gb (x32) | 1.8V - 1.8V | 202FBGA | - |

MCP: OneNAND/DRAM/OneNAND

| Memory | Flex-OneNAND Density | DRAM Density (Org.) | Voltages (NAND-DRAM) | MCP Package | PoP Package |
|-----------------------------|----------------------|---------------------|----------------------|-------------|-------------|
| OneNAND & DRAM & OneDRAM | 2Gb | 1Gb (x16) | 1.8V - 1.8V | | 216FBGA |

MCP: moviNAND/NAND/DRAM

| Memory | movi & NAND Density | DRAM Density (Org.) | Voltages (NAND-DRAM) | MCP Package | Remark |
|-------------|---------------------|---------------------|----------------------|-------------|--------|
| | 512Mb | 256Mb(x16,x32) | 2.7V/1.8V - 1.8V | 107/137FBGA | |
| | O I ZIVID | 512Mb (x16,x32) | 2.7V/1.8V - 1.8V | 107/137FBGA | |
| | | 256Mb (x16,x32) | 3.0V/1.8V - 1.8V | 107/137FBGA | |
| moviNAND & | 1Gb | 512Mb (x16,x32) | 2.7V/1.8V - 1.8V | 107/137FBGA | |
| NAND & DRAM | | 1Gb (x32) | 1.8V - 1.8V | 137FBGA | |
| | 2Gb | 512Mb (x16,x32) | 1.8V - 1.8V | 107/137FBGA | |
| | 200 | 1Gb (x16,x32) | 1.8V - 1.8V | 107/137FBGA | |
| | 4Gb | 1Gb (x32) | 2.7V - 1.8V | 137FBGA | |

MCP: NOR/Utram

| Memory | NOR Density | UtRAM Density (Org.) | Voltages (NOR-UtRAM) | MCP Package | Remark |
|-------------|-------------|----------------------|----------------------|-------------|--------|
| | 512Mb | 128Mb | 1.8V - 1.8V | 107FBGA | |
| | 256Mb | 128Mb | 1.8V - 1.8V | 107FBGA | |
| NOR & Utram | | | 1.8V - 1.8V | 56FBGA | |
| | 128Mb | 64Mb | 1.8V - 1.8V | 84/88FBGA | |
| | 1 Z 8 IVID | 32Mb | 1.8V - 1.8V | 84/88FBGA | |

MCP: NOR/DRAM

| Memory | NOR Density | DRAM Density (Org.) | Voltages (NOR-DRAM) | Package | Remark |
|------------|-------------|---------------------|---------------------|---------|--------|
| NOR & DRAM | 512Mb | 128Mb (x16) | 1.8V - 1.8V | 103FBGA | |
| | | 256Mb (x16) | 1.8V - 1.8V | 103FBGA | |

Please contact your local Samsung sales representative for latest product offerings. Note: All parts are lead free

22

moviNAND™

moviNAND combines high-density MLC NAND Flash with an MMC controller in a single chip that has an MMC interface. moviNAND delivers dense, cost-effectice storage for embedded applications.

| Density | Package Type | Org. | Vol (V) | Remarks |
|---------|--------------|------|---------|---|
| 2GB | FBGA | x8 | 1.8/3.3 | MMC 4.3 & MMC 4.4 |
| 4GB | FBGA | x8 | 1.8/3.3 | |
| 8GB | FBGA | x8 | 1.8/3.3 | |
| 16GB | FBGA | х8 | 1.8/3.3 | Contact your local Samsung rep for availability and ordering information. |
| 32GB | FBGA | х8 | 1.8/3.3 | ordoning information. |
| 64GB | FBGA | x8 | 1.8/3.3 | |

Please contact your local Samsung sales representative for the latest product offerings. Note: All parts are lead free

OneDRAM™

OneDRAM is a dual-port, low-power DRAM with an SRAM buffer interface and is optimal for high-performance, high-density mobile applications.

| Density | Part Number | Package Type | Org. | Vol (V) | Temp. | Speed |
|---------|-------------------|------------------|-----------------------|---------|-----------|---------|
| | KJA51Z23PC-AA0 | 216FBGA (14x14) | A-port: x16 (SDR/DDR) | | | 4001411 |
| 512Mb | NJAJ I ZZJF O-AAO | 2101 DOM (14X14) | B-port: x16 (SDR/DDR) | 1.8V | extended | |
| STZIVID | KJA51Y23PC-AA0 | 152FBGA (14x14) | A-port: x16 (SDR/DDR) | 1.00 | exteriueu | 133MHz |
| | NJAD I 125F G-AAU | 132FBQA (14X14) | B-port: x16 (SDR/DDR) | | | |
| | I/ IA4 OMOEDD EAO | | A-port: x32SDR | | | 166MHz |
| | KJA1GW25PD-EA0 | | B-port: x32DDR" | | | |
| | I/ IA1074EDD EA0 | | A-port: x16DDR | | | |
| 1Gb | KJA1GZ45PD-EAO | 240FBGA (14x14) | B-port: x32DDR" | 1.8V | extended | |
| TGD | KJA1GZ45PD-EAO | 2401 DOM (14X14) | A-port: x16DDR | 1.00 | exterided | |
| | NJA I GZ4JF D-LAO | | B-port: x16DDR" | | | |
| | KJA1GY25PD-EAO | | A-port: x16SDR | | | |
| | NOATGIZOI D-LAO | | B-port: x32DDR" | | | |

Please contact your local Samsung sales representative for the latest product offerings. Note: All parts are lead free

3.5" Hard Disk Drives

| Family | Capacity (GB) | RPM | Interface | Buffer | Sector | Model |
|--------|---------------|------|---------------|--------|--------|---------|
| | 80 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD083GJ |
| | 80 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD084GJ |
| | 160 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD161GJ |
| | 160 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD162GJ |
| | 250 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD251HJ |
| | 250 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD252HJ |
| | 320 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD321HJ |
| F1DT | 320 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD322HJ |
| | 500 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD501IJ |
| | 500 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD502IJ |
| | 640 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD642JJ |
| | 750 | 7200 | SATA-2 | 16 | 512 | HD752LJ |
| | 750 | 7200 | SATA 3.0 Gbps | 32 | 512 | HD753LJ |
| | 1 TB | 7200 | SATA 3.0 Gbps | 16 | 512 | HD102UJ |
| | 1 TB | 7200 | SATA 3.0 Gbps | 32 | 512 | HD103UJ |
| | 500 | 5400 | SATA 3.0 Gbps | 16 | 512 | HD502HI |
| F2EG | 1 TB | 5400 | SATA 3.0 Gbps | 32 | 512 | HD103SI |
| | 1.5 TB | 5400 | SATA 3.0 Gbps | 32 | 512 | HD154UI |
| | 160 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD164GJ |
| | 250 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD254GJ |
| | 320 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD324HJ |
| | 160 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD163GJ |
| F3 | 250 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD253GJ |
| | 320 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD323HJ |
| | 500 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD502HJ |
| | 750 | 7200 | SATA 3.0 Gbps | 32 | 512 | HD754JJ |
| | 1TB | 7200 | SATA 3.0 Gbps | 32 | 512 | HD103SJ |
| | 250 | - | SATA 3.0 Gbps | 16 | 512 | HD253GI |
| | 320 | - | SATA 3.0 Gbps | 16 | 512 | HD324HI |
| | 500 | - | SATA 3.0 Gbps | 16 | 512 | HD503HI |
| F3EG | 750 | - | SATA 3.0 Gbps | 32 | 512 | HD754JI |
| | 1TB | - | SATA 3.0 Gbps | 32 | 512 | HD105SI |
| | 1.5 TB | - | SATA 3.0 Gbps | 32 | 512 | HD153WI |
| | 2 TB | - | SATA 3.0 Gbps | 32 | 512 | HD203WI |
| | 160 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD165GJ |
| | 160 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD166GJ |
| F4 | 250 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD255GJ |
| | 250 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD255GJ |
| | 320 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD323HJ |

3.5" Enterprise RAID Drives

| Family | Capacity (GB) | RPM | Interface | Buffer | Sector | Model |
|--------|---------------|------|---------------|--------|--------|---------|
| | 250 | 7200 | SATA 3.0 Gbps | 16 | 512 | HE252HJ |
| | 320 | 7200 | SATA 3.0 Gbps | 16 | 512 | HE322HJ |
| F1R | 500 | 7200 | SATA 3.0 Gbps | 16 | 512 | HE502IJ |
| FIK | 640 | 7200 | SATA 3.0 Gbps | 16 | 512 | HE642JJ |
| | 750 | 7200 | SATA 3.0 Gbps | 32 | 512 | HE753LJ |
| | 1 TB | 7200 | SATA 3.0 Gbps | 32 | 512 | HE103UJ |
| | 250 | 7200 | SATA 3.0 Gbps | 16 | 512 | HE253GJ |
| F3R | 500 | 7200 | SATA 3.0 Gbps | 16 | 512 | HE502HJ |
| F3H | 750 | 7200 | SATA 3.0 Gbps | 32 | 512 | HE754JJ |
| | 1 TB | 7200 | SATA 3.0 Gbps | 32 | 512 | HE103SJ |

2.5" Hard Disk Drives

| Family | Capacity (GB) | RPM | Interface | Buffer | Sector | Model |
|--------|---------------|------|---------------|--------|--------|---------|
| | 160 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM161GI |
| | 250 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM251HI |
| M7E | 320 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM321HI |
| | 500 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM501JI |
| | 640 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM641JI |
| | 120 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM120JI |
| | 160 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM161JI |
| M7 | 250 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM250II |
| IVI7 | 320 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM320HI |
| | 400 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM400HI |
| | 500 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM500GI |
| MP4 | 250 | 7200 | SATA 3.0 Gbps | 16 | 512 | HM250HJ |
| | 320 | 7200 | SATA 3.0 Gbps | 16 | 512 | HM320HJ |
| | 500 | 7200 | SATA 3.0 Gbps | 16 | 512 | HM500JJ |
| | 640 | 7200 | SATA 3.0 Gbps | 16 | 512 | HM640JJ |
| MT2 | 750 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM750LI |
| IVIIZ | 1 TB | 5400 | SATA 3.0 Gbps | 8 | 512 | HM100UI |

BD-COMBO

| Interface | Speed | Туре | Loading | Lightscribe | Medel |
|-----------|-----------------|------|---------|-------------|---------------------|
| SATA | BD ROM READ 8X | Н/Н | Tray | X | TS-HB33A / SH-B083A |
| | | | | 0 | TS-HB33L / SH-B083L |
| | BD ROM READ 12X | H/H | Tray | X | TS-HB43A / SH-B123A |
| | | | | 0 | TS-HB43L / SH-B123L |
| | BD-ROM READ 4X | Slim | Tray | X | TS-LB23A / SN-B043A |
| | | | | | TS-LB23B |
| | | | | | TS-LB23D |
| | | | | 0 | TS-LB23L / SN-B043L |
| | | | | | TS-LB23P |
| | | | Slot | 0 | TS-TB23L |

DVD-W

| Interface | Speed | Туре | Loading | Lightscribe | Medel |
|-----------|---------------|---------------|---------|-------------|---------------------|
| SATA | DVD Write 22X | H/H | Tray | X | TS-H653G |
| | DVD Write 20X | H/H | Tray | Х | TS-H653H |
| | DVD Write 20X | H/H | Tray | Х | TS-H653J |
| PATA | DVD Write 22X | H/H | Tray | Х | TS-H662A / SH-S222A |
| | DVD Write 22X | H/H | Tray | X | TS-H663C / SH-S223C |
| SATA | DVD Write 24X | H/H | Tray | X | TS-H663D / SH-S243D |
| SAIA | DVD Write 22X | H/H | Tray | 0 | TS-H653R |
| | DVD Write 16X | H/H | Tray | 0 | TS-H653T |
| PATA | DVD Write 22X | H/H | Tray | 0 | TS-H662L / SH-S222L |
| CATA | DVD Write 22X | H/H | Tray | 0 | TS-H663L / SH-S223L |
| SATA | DVD Write 24X | H/H | Tray | 0 | TS-H663N / SH-S243N |
| | | | | | TS-L633B / SN-S083B |
| | | | | X | TS-L633C / SH-S083C |
| | | | | ^ | TS-L633F / SN-S083F |
| | | | Tray | | TS-L633J |
| | | Slim | | | TS-L633N / SN-S083N |
| | | | | 0 | TS-L633R / SN-S083R |
| SATA | DVD Write 8X | | | | TS-L633Y |
| | | | Olet | X | TS-T633C / SN-T083C |
| | | | Slot | 0 | TS-T633P |
| | | | Trans | V | TS-U633F |
| | | Lillara Oliva | Tray | X | TS-U633J / SU-S083J |
| | | Ultra Slim | Clot | V | TS-D633A |
| | | | Slot | X | TS-D633C |

DVD-W Slim External

| Interface | Speed | Туре | Loading | Lightscribe | Medel |
|-----------|--------------|------------|---------|-------------|----------|
| USB 2.0 | DVD Write 8X | Slim | Tray | X | SE-S084C |
| | | Ultra Slim | Tray | X | SE-S084D |
| | | Slim | Tray | X | SE-S084F |
| | | | Slot | 0 | SE-T084P |

DVD-ROM

| Interface | Speed | Туре | Loading | Lightscribe | Medel |
|-----------|---------|-----------|---------|-------------|---------------------|
| SATA | DVD 16X | H/H | Tray | X | TS-H353C / SH-D163J |
| | DVD 8X | Slim | Tray | X | TS-L333B |
| | | | | | TS-L333D |
| | DVD 8X | Utra Slim | Tray | X | TS-U333A |

DVD-W Loader

| Interface | Speed | Туре | Loading | Lightscribe | Medel |
|-----------|--------|------|---------|-------------|----------|
| PATA | DVD 8X | H/H | Tray | X | TS-P632F |



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